

DMTH6005LPS

60V +175°C N-CHANNEL ENHANCEMENT MODE MOSFET PowerDI5060-8

Product Summary

BV _{DSS}	R _{DS(ON)} max	I _D T _C = +25°C (Note 9)
60V	$5.5 \text{m}\Omega$ @ $V_{GS} = 10V$	100A

Description and Applications

This MOSFET is designed to minimize the on-state resistance (R_{DS(ON)}) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

PowerDI5060-8

- High Frequency Switching
- Sync. Rectification
- **DCDC** Converters

Features

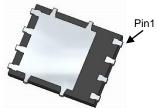
- Rated to +175°C Ideal for High Ambient Temperature **Environments**
- 100% Unclamped Inductive Switching ensures more reliable and robust end application
- $\begin{array}{l} \text{Low } R_{DS(ON)} \text{minimizes power losses} \\ \text{Low } Q_g \text{minimizes switching losses} \end{array}$
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- An Automotive-Compliant Part is Available Under Separate Datasheet (DMTH6005LPSQ)

Mechanical Data

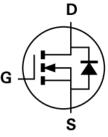
- Case: PowerDI[®]5060-8
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.097 grams (Approximate)



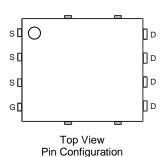




Bottom View



Internal Schematic



Ordering Information (Note 4)

Part Number	Case	Packaging
DMTH6005LPS-13	PowerDI5060-8	2,500 / Tape & Reel

Notes:

- 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/

Marking Information



⊃¦¦ = Manufacturer's Marking H6005LS = Product Type Marking Code YYWW = Date Code Marking YY = Year (ex: 18 = 2018) WW = Week (01 to 53)

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Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Drain-Source Voltage		V_{DSS}	60	V
Gate-Source Voltage		V _{GSS}	±20	V
Continuous Drain Current (Note 5)	$T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$	I _D	20.6 17.2	А
Continuous Drain Current (Note 6)	$T_{C} = +25^{\circ}C$ (Note 9) $T_{C} = +100^{\circ}C$	I _D	100 90	Α
Maximum Continuous Body Diode Forward Current (Note 6)	Is	100	А	
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)		I _{DM}	160	Α
Avalanche Current, L = 1mH		I _{AS}	14.8	Α
Avalanche Energy, L = 1mH		Eas	98	mJ

Thermal Characteristics

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)	$T_A = +25^{\circ}C$	P_{D}	3.2	W
Thermal Resistance, Junction to Ambient (Note 5)		$R_{\theta JA}$	47	°C/W
Total Power Dissipation (Note 6)	$T_C = +25^{\circ}C$	P_D	150	W
Thermal Resistance, Junction to Case (Note 6)		R _{0JC}	1	°C/W
Operating and Storage Temperature Range		T _{J,} T _{STG}	-55 to +175	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

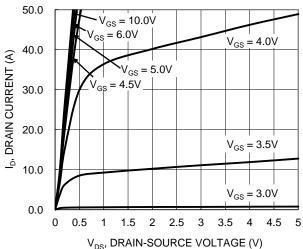
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)						•	
Drain-Source Breakdown Voltage	BV _{DSS}	60	_	_	V	$V_{GS} = 0V$, $I_D = 1mA$	
Zero Gate Voltage Drain Current	I _{DSS}	_	_	1	μA	$V_{DS} = 48V, V_{GS} = 0V$	
Gate-Source Leakage	I _{GSS}	_	_	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)			•				
Gate Threshold Voltage	V _{GS(TH)}	1	_	3	V	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	
		_	4.4	5.5	mΩ	$V_{GS} = 10V, I_D = 50A$	
Static Drain-Source On-Resistance	R _{DS(ON)}	_	5.7	7.2		$V_{GS} = 6V, I_{D} = 20A$	
	, , ,	_	7.7	10		$V_{GS} = 4.5V, I_D = 12.5A$	
Diode Forward Voltage	V_{SD}	_	0.9	_	V	$V_{GS} = 0V, I_{S} = 50A$	
DYNAMIC CHARACTERISTICS (Note 8)							
Input Capacitance	C _{iss}	_			.,		
Output Capacitance	Coss	_	965.2	_	pF	$V_{DS} = 30V$, $V_{GS} = 0V$, $f = 1MHz$	
Reverse Transfer Capacitance	C _{rss}	_	59.8	_			
Gate Resistance	Rg	_	0.66	_	Ω	$V_{DS} = 0V$, $V_{GS} = 0V$, $f = 1MHz$	
Total Gate Charge (V _{GS} = 10V)	Qg	_	47.1	_			
Total Gate Charge (V _{GS} = 4.5V)	Qg	_	23.1	_			
Gate-Source Charge	Q _{gs}	_	10.2	_	nC	$V_{DD} = 30V, I_{D} = 50A$	
Gate-Drain Charge	Q_{gd}	_	12.5	_			
Turn-On Delay Time	t _{D(ON)}	_	8.3	_			
Turn-On Rise Time	t _R	_	9.4	_		$V_{DD} = 30V, V_{GS} = 10V,$	
Turn-Off Delay Time	t _{D(OFF)}	_	22	_	ns	$I_D = 30A, R_G = 3.3\Omega$	
Turn-Off Fall Time	t _F	_	8.9	_			
Body Diode Reverse Recovery Time	t _{RR}	_	40.4	_	ns		
Body Diode Reverse Recovery Charge	Q _{RR}	_	49.7	_	nC	$I_F = 30A$, di/dt = 100A/ μ s	

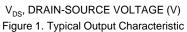
Notes:

- Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1inch square copper plate.
 Thermal resistance from junction to soldering point (on the exposed drain pad).
 Short duration pulse test used to minimize self-heating effect.
 Guaranteed by design. Not subject to product testing.
 Package limited.

DMTH6005LPS







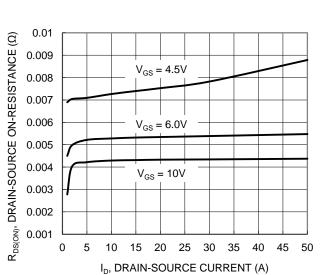


Figure 3. Typical On-Resistance vs. Drain Current and Gate Voltage

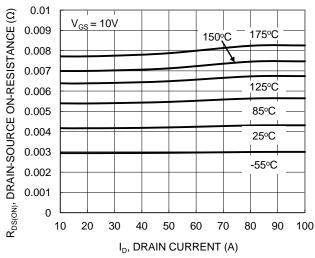


Figure 5. Typical On-Resistance vs. Drain Current and Junction Temperature

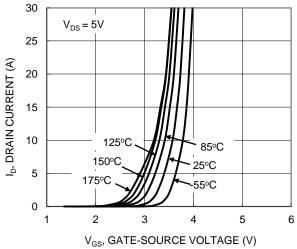


Figure 2. Typical Transfer Characteristic

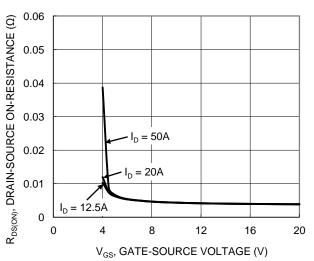


Figure 4. Typical Transfer Characteristic

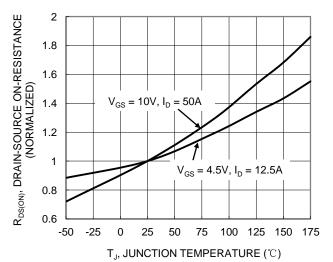


Figure 6. On-Resistance Variation with Junction Temperature



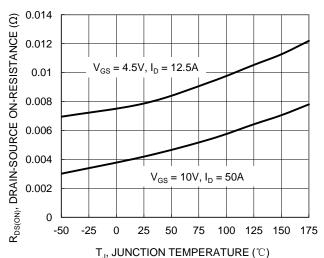
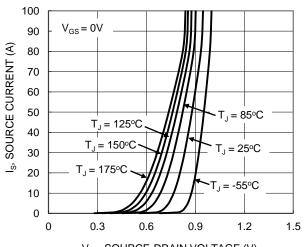
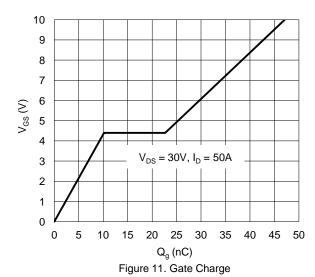


Figure 7. On-Resistance Variation with Junction Temperature



 V_{SD} , SOURCE-DRAIN VOLTAGE (V) Figure 9. Diode Forward Voltage vs. Current



 $V_{GS(TH)},$ GATE THRESHOLD VOLTAGE (V) 3.5 3 $I_D = 1mA$ 2.5 2 $I_{D} = 250 \mu A$ 1.5 1 0.5

4

0

-50

-25

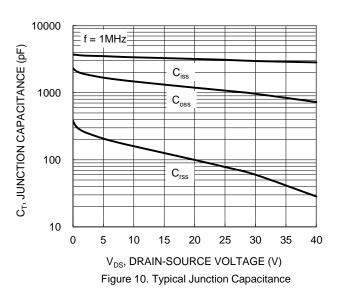
T_.I, JUNCTION TEMPERATURE (°C) Figure 8. Gate Threshold Variation vs. Junction Temperature

50

75

100 125 150 175

25



1000 R_{DS(ON)} Limited 100 ID, DRAIN CURRENT (A) 10 1 T_{J(Max)} = 175°C T_C = 25°C Single Pulse 0.1 **DUT** on Infinite Heatsink $V_{GS} = 10V$ 0.01 0.1 10 100 V_{DS} , DRAIN-SOURCE VOLTAGE (V) Figure 12. SOA, Safe Operation Area



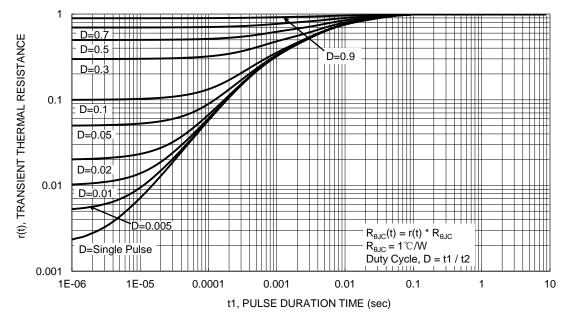


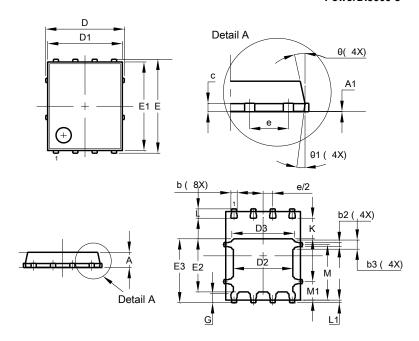
Figure 13. Transient Thermal Resistance



Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI5060-8

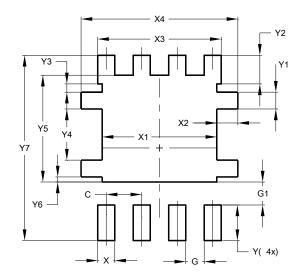


PowerDI5060-8					
Dim	Min Max		Тур		
Α	0.90	1.10	1.00		
A1	0.00	0.05	-		
b	0.33	0.51	0.41		
b2	0.200	0.350	0.273		
b3	0.40	0.80	0.60		
C	0.230	0.330	0.277		
D	5.15 BSC				
D1	4.70	5.10	4.90		
D2	3.70	4.10	3.90		
D3	3.90	4.30	4.10		
Е	6.15 BSC				
E1	5.60	6.00	5.80		
E2	3.28	3.68	3.48		
E3	3.99	4.39	4.19		
е	1.27 BSC				
G	0.51	0.71	0.61		
K	0.51	-	-		
L	0.51	0.71	0.61		
L1	0.100	0.200	0.175		
М	3.235	4.035	3.635		
M1	1.00	1.40	1.21		
Θ	10°	12°	11°		
Θ1	6°	8°	7°		
All Dimensions in mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI5060-8



Dimensions	Value (in mm)			
С	1.270			
G	0.660			
G1	0.820			
Х	0.610			
X1	4.100			
X2	0.755			
Х3	4.420			
X4	5.610			
Υ	1.270			
Y1	0.600			
Y2	1.020			
Y3	0.295			
Y4	1.825			
Y5	3.810			
Y6	0.180			
Y7	6.610			



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